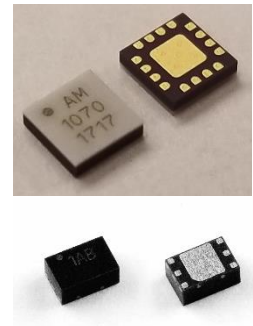


AM1070 - Amplifier

DC to 18 GHz Gain Block

Description

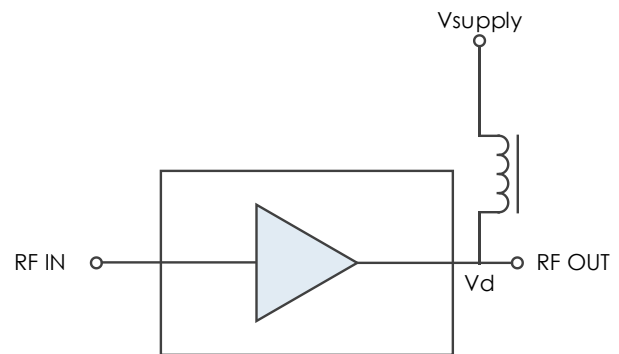
The AM1070 is a DC-coupled broadband gain block covering up to 18 GHz. The device exhibits high third order intercept performance, excellent gain stability over the operating temperature range, and a gain flatness within +/- 1 dB of nominal gain useful in many broadband applications. With internal 50Ω matching and packaged in either a 3mm QFN or a 1.3mm x 2mm DFN, the AM1070 represents a compact total PCB footprint.



Features

- 12 dB Gain
- 3.0 dB Noise Figure
- +27 dBm OIP3
- +15 dBm P1dB
- +3.3V, 60 mA Supply
- 3mm QFN or 1.3mm x 2mm DFN
- -40C to +85C Operation

Functional Diagram



Characteristic Performance

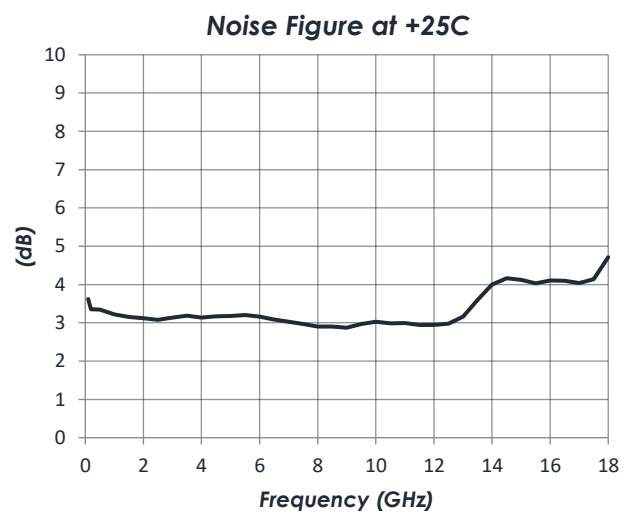
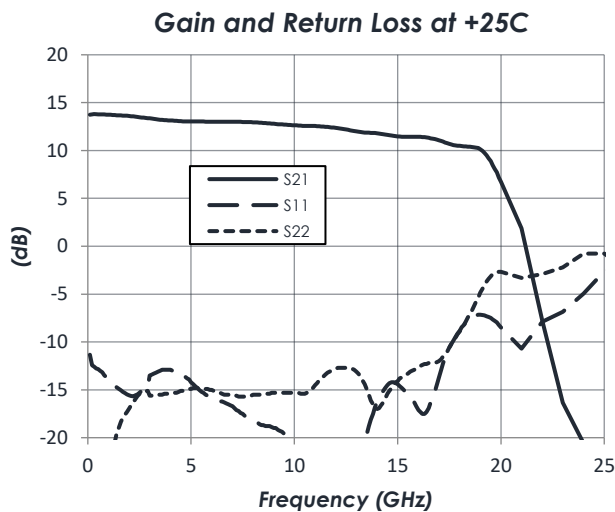


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Revision History

Date	Revision Number	Notes
February 23, 2017	1	Initial Release
April 9, 2024	2	Updated to latest datasheet format. More comprehensive data added. Added pinout and evaluation board image for AM1070-2

AM1070 - Amplifier

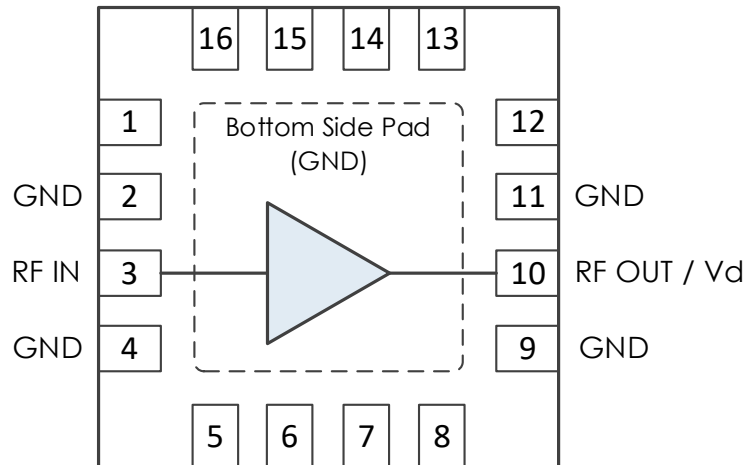
DC to 18 GHz Gain Block



Pin Layout and Definitions

3mm QFN

NOTE: All Non-Named Pins Are NC or GND



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground – Common
3	RF In	RF Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
4	GND	Ground – Common
5 – 8	NC	Not Connected*
9	GND	Ground – Common
10	RF Out / Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required.
11	GND	Ground – Common
12 - 16	NC	Not Connected*
Bottom Pad	GND	Ground – Common

*Note: NC pins may be left floating or grounded. Grounding these pins is recommended.

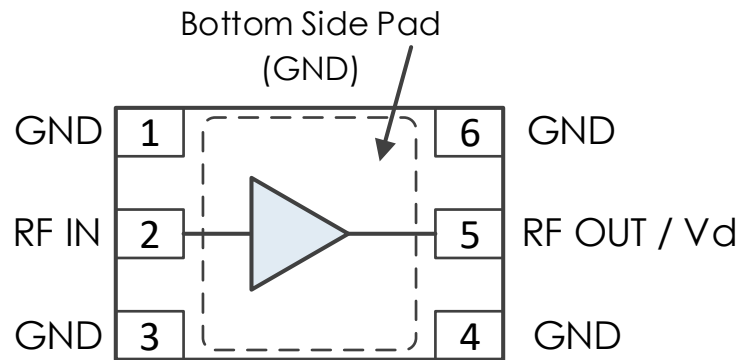
AM1070 - Amplifier

DC to 18 GHz Gain Block



Pin Layout and Definitions (continued)

1.3mm x 2mm DFN



Pin Number	Pin Name	Pin Function
1	GND	Ground - Common
2	RF In	RF Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
3,4	GND	Ground - Common
5	RF Out, Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
6	GND	Ground - Common
Case GND	GND	Ground - Common

AM1070 - Amplifier

DC to 18 GHz Gain Block



Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+6.0 V
RF Input Power		+13 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-55 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	AM1070-1	MSL 1
	AM1070-2	MSL 3



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+3.3 V	+3.6 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	99.6

AM1070 - Amplifier

DC to 18 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage		+3.0 V	+3.3 V	+3.6 V
DC Device Voltage, Vd		+2.7 V	+3.1 V	+3.3 V
DC Device Current, Id	Vd = +3.1 V	45 mA	60 mA	75 mA
Power Dissipated	Vd = +3.1 V	0.12 W	0.19 W	0.25 W

RF Performance

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		DC		18 GHz
Gain			12 dB	
Return Loss			15 dB	
Output IP3			+27 dBm	
Output P1dB			+15 dBm	
Noise Figure			3.0 dB	

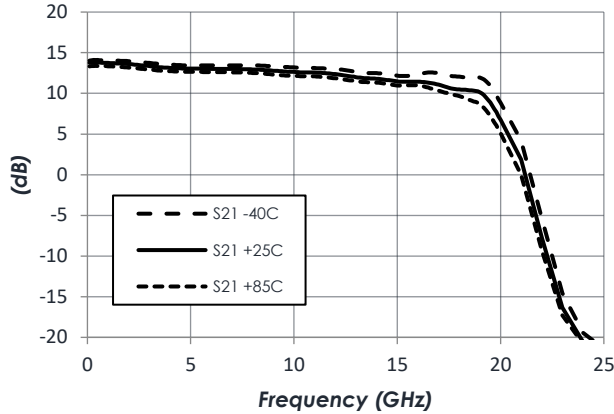
AM1070 - Amplifier

DC to 18 GHz Gain Block

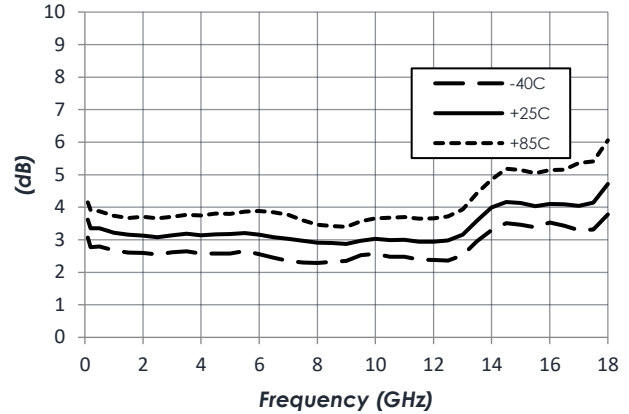
Typical Performance

(Vd = 3.1V, Id = 60mA, T=25C unless otherwise specified)

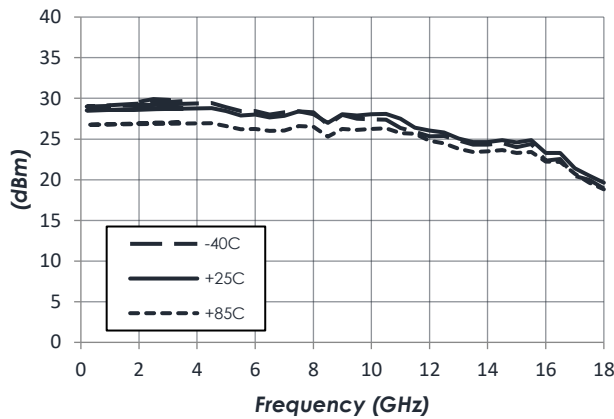
Gain vs Temperature



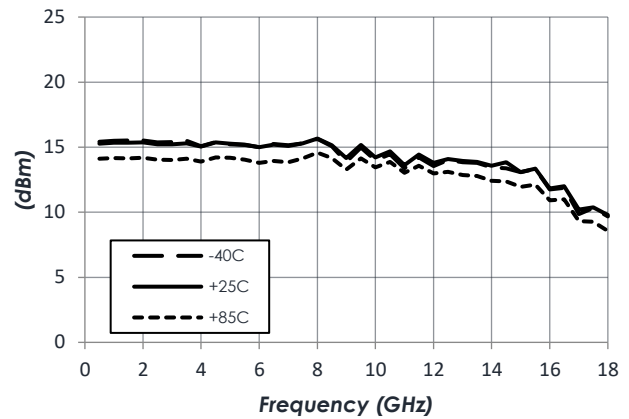
Noise Figure vs Temperature



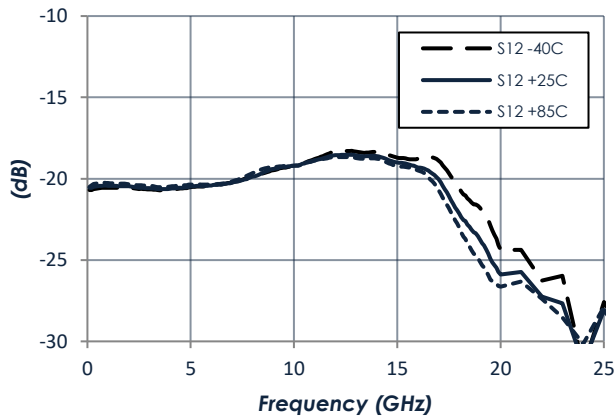
Output IP3 vs Temperature



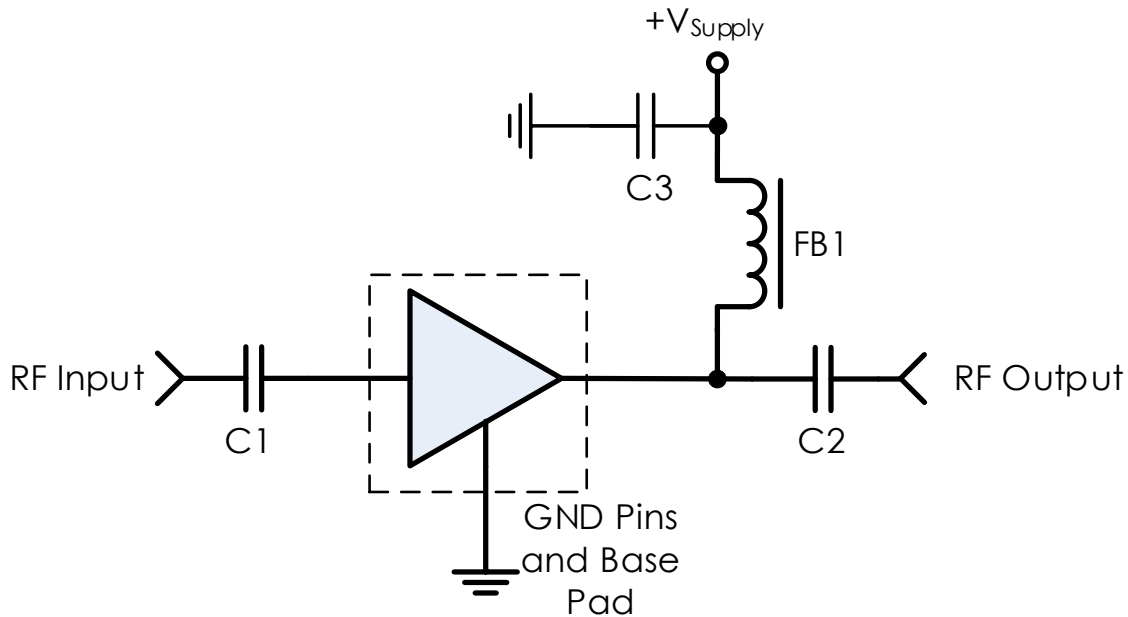
P1dB vs Temperature



Reverse Isolation vs Temperature



Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0201BB104KW160	Passive Plus
C3	0.1 μ F	GRM155R71C104KA88	Murata
FB1	-	MMZ1005A222E	TDK

Notes:

1. NC pins may be floating or grounded. Grounding these pins is recommended.
2. DC blocking capacitors should be high-performance, low-loss capacitors for optimum performance.

AM1070 - Amplifier

DC to 18 GHz Gain Block

Part Ordering Details

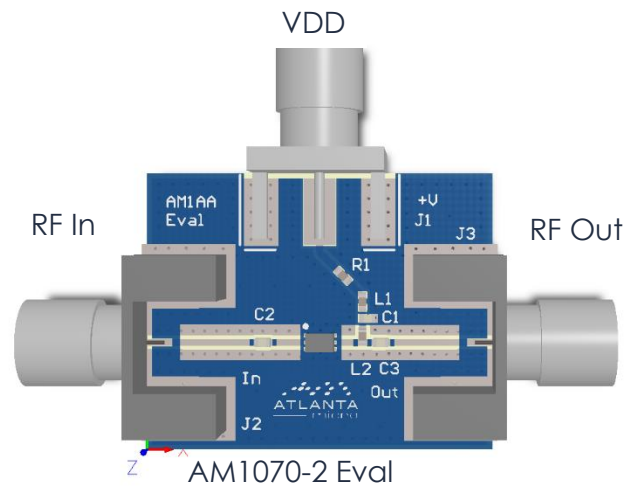
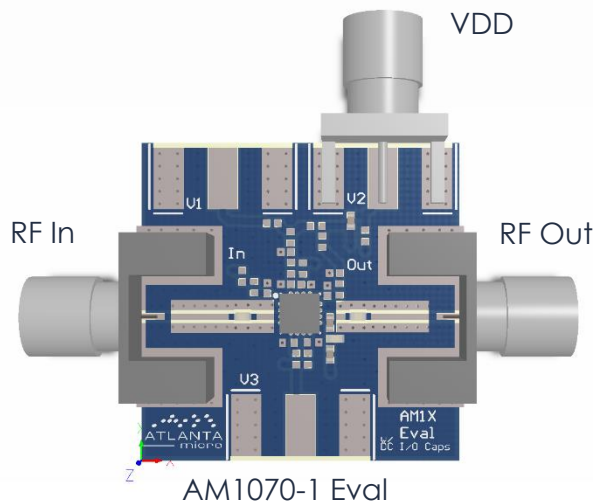
Description	Part Number
3mm 16 Lead QFN	AM1070-1
1.3mm x 2mm 6 Lead DFN	AM1070-2
AM1070-1 Evaluation Board	AM1070-1 Eval
AM1070-2 Evaluation Board	AM1070-2 Eval

Related Parts

Part Number	Description
AM1071	DC to 18 GHz +5.0V Gain Block
AM1102	DC to 22 GHz Broadband Low Noise Amplifier
AM1063-1	DC to 10 GHz Gain Block
AM1063-2	DC to 10 GHz Miniature Gain Block
AM1163-1	DC to 10 GHz Low Noise Amplifier
AM1163-2	DC to 10 GHz Miniature Low Noise Amplifier
AM1053	5 GHz to 20 GHz Gain Block / Driver Amplifier
AM1082	5 GHz to 17 GHz Gain Block / Driver Amplifier

Evaluation PC Board

(Not all components shown will necessarily be installed)



Component Compliance Information

RoHS: Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.